

View Online at <https://aerobasegroup.com/nsn/5961-01-227-5784>

Inclosure Material:

Metal

Overall Length:

0.840 inches

Overall Height:

0.910 inches

Overall Width:

0.619 inches

Mounting Facility Quantity:

4

Component Name And Quantity:

2 semiconductor device diode

Mounting Method:

Threaded hole

Features Provided:

Hermetically sealed case

Thread Size:

0.112 inches

Semiconductor Material:

Silicon all semiconductor device diode

Voltage Rating In Volts Per Characteristic:

54.0 repetitive peak reverse voltage all semiconductor device diode and 45.0 working peak reverse voltage all semiconductor device diode and 45.0 reverse voltage, instantaneous all semiconductor device diode

Current Rating Per Characteristic:

75.00 amperes forward current, average all semiconductor device diode

Power Rating Per Characteristic:

75.0 watts small-signal input power, common-collector absolute all semiconductor device diode

Maximum Operating Temperature Per Measurement Point:

175.0 degrees celsius junction

Thread Series Designator:

Unc

Terminal Type And Quantity:

4 turret

Shelf Life:

N/a

Unit Of Measure:

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Demilitarization:

Yes - demil/mli

Fiig:

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